



**New EAM potential for the Ni-Al system
and
Application to the martensitic
transformation in B2-NiAl**

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Development a new Ni-Al potential

Motivation

Some of the existing potentials for the Ni-Al system:

- ◆ **Voter and Chen** (MRS Proc., 1987)
- ◆ **Foiles and Daw** (JRM, 1987)
- ◆ **“B2-potential”** (Phys. Rev. B, 2002)
 - ◆ **Strengths:** Accurate fit to phase stability, point defect, GSF’s and many other properties of B2-NiAl.
 - ◆ **Weaknesses:** less accurate for L1₂-Ni₃Al. Poor quality of the pure Ni and Al potentials
- ◆ **“Ni₃Al-potential”** (Acta Mater., 2004)
 - ◆ **Strengths:** excellent fit to Ni₃Al properties. Reproduces phase stability and the Ni-Al phase diagram.
 - ◆ **Weaknesses:** Less accurate for B2-NiAl. The pure Ni and Al potentials are accurate but Al is different from the widely used “Al-99”

Goals of the potential development

- ❖ Cross-fit our most favorite potentials “Al-99” and “Ni-04”
- ❖ Make it applicable to NiAl particles in Al matrix
- ❖ Further improve phase stability, with nearly accurate fits for both the B2 and L1₂ phases
- ❖ Check is the new potential will automatically reproduce the B2-L1₀ martensitic transformation

Approach:

- Use a larger database (experimental and *ab initio*) and improved fitting/testing methodologies
- Extensive testing for properties, especially the martensitic transformation

Fitting and testing procedures

Database

- ❖ Experimental properties:

Lattice parameter, cohesive energy and elastic constants of B2-NiAl

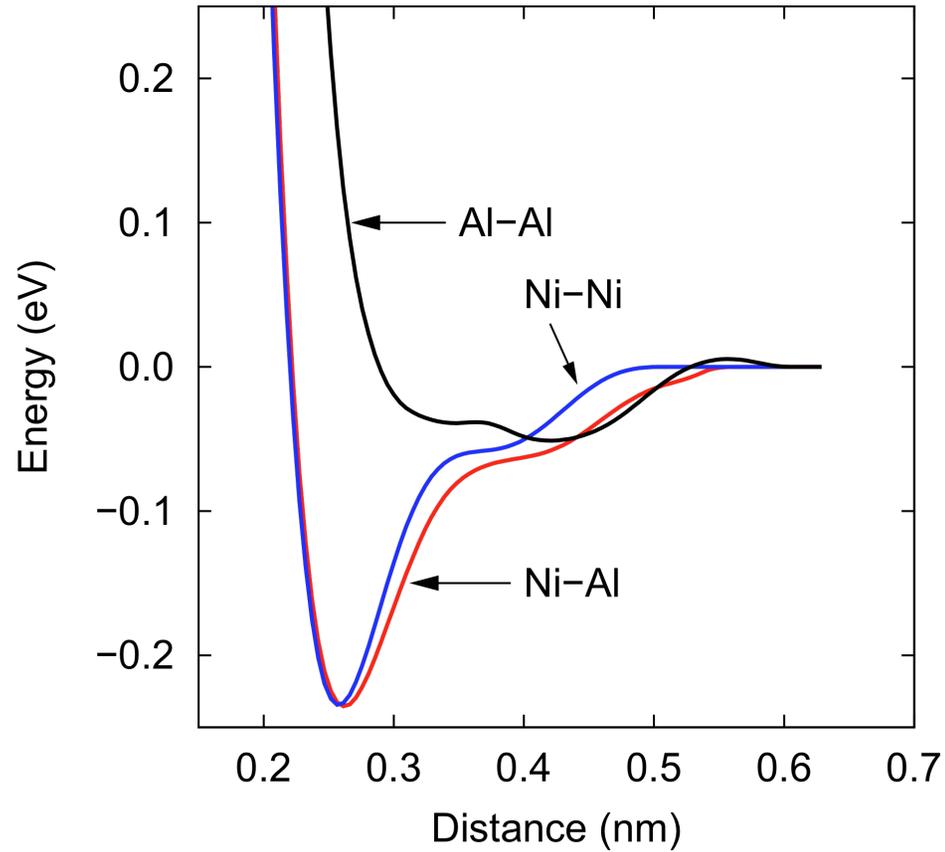
- ❖ Ab initio data:

Formation energies of several stable or unstable intermetallic compounds across the entire composition range

Optimization

- ❑ Minimization of mean-squared deviation from target properties. The weights control the priority of properties
- ❑ Simulated annealing by the simplex method

Potential functions



Pair-interaction functions of the Ni-Al potentials shown in the effective pair format.

Properties of B2-NiAl

Lattice properties

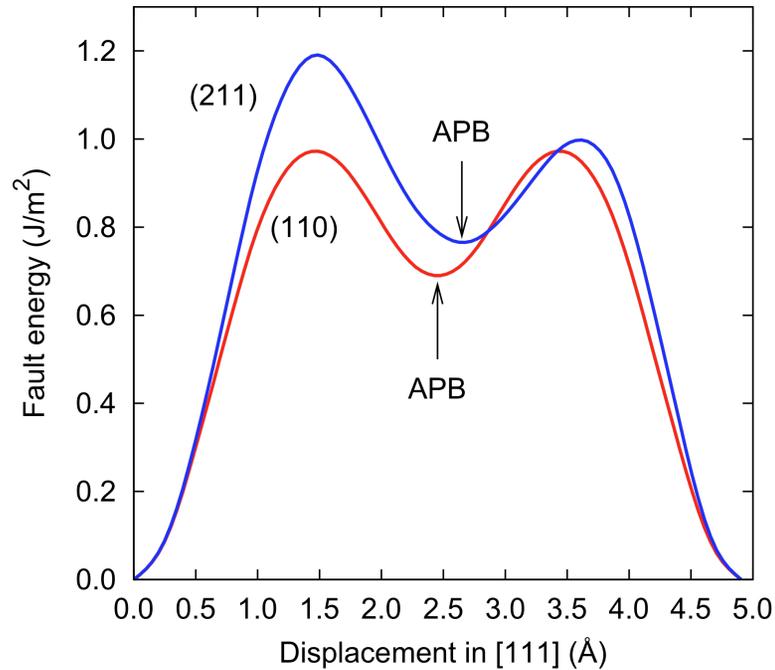
	Experiment	EAM (present)	“B2-NiAl”	
a_0 (Å)	2.88	2.8320	2.86	
E_f (eV)	-0.70	-0.6059	-0.56	←
E_0 (eV/atom)	-4.50	-4.5109	-4.47	←
c_{11} (GPa)	199	191	200	←
c_{12} (GPa)	137	143	140	
c_{44} (GPa)	116	121	120	

Surfaces and interfaces

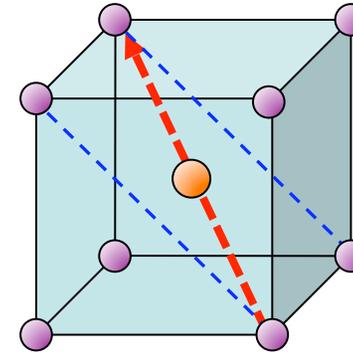
	Experiment	<i>Ab initio</i>	EAM (present)	“B2-NiAl”	
Surface					
(100)		2.85, 2.75	2.12	1.67	←
(110)		2.05, 1.87, 1.79, 1.37	1.89	1.25	←
(111)			2.20	1.63	←
APB					
(110)	>0.50	0.88, 0.81	0.65	0.55	←
(211)	>0.75	0.89, 0.99	0.73	0.72	

Generalized stacking faults in B2-NiAl

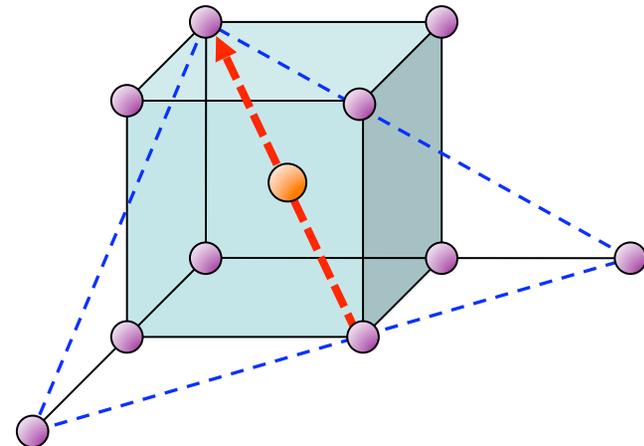
Gamma-surfaces



$\langle 111 \rangle \{011\}$ slip

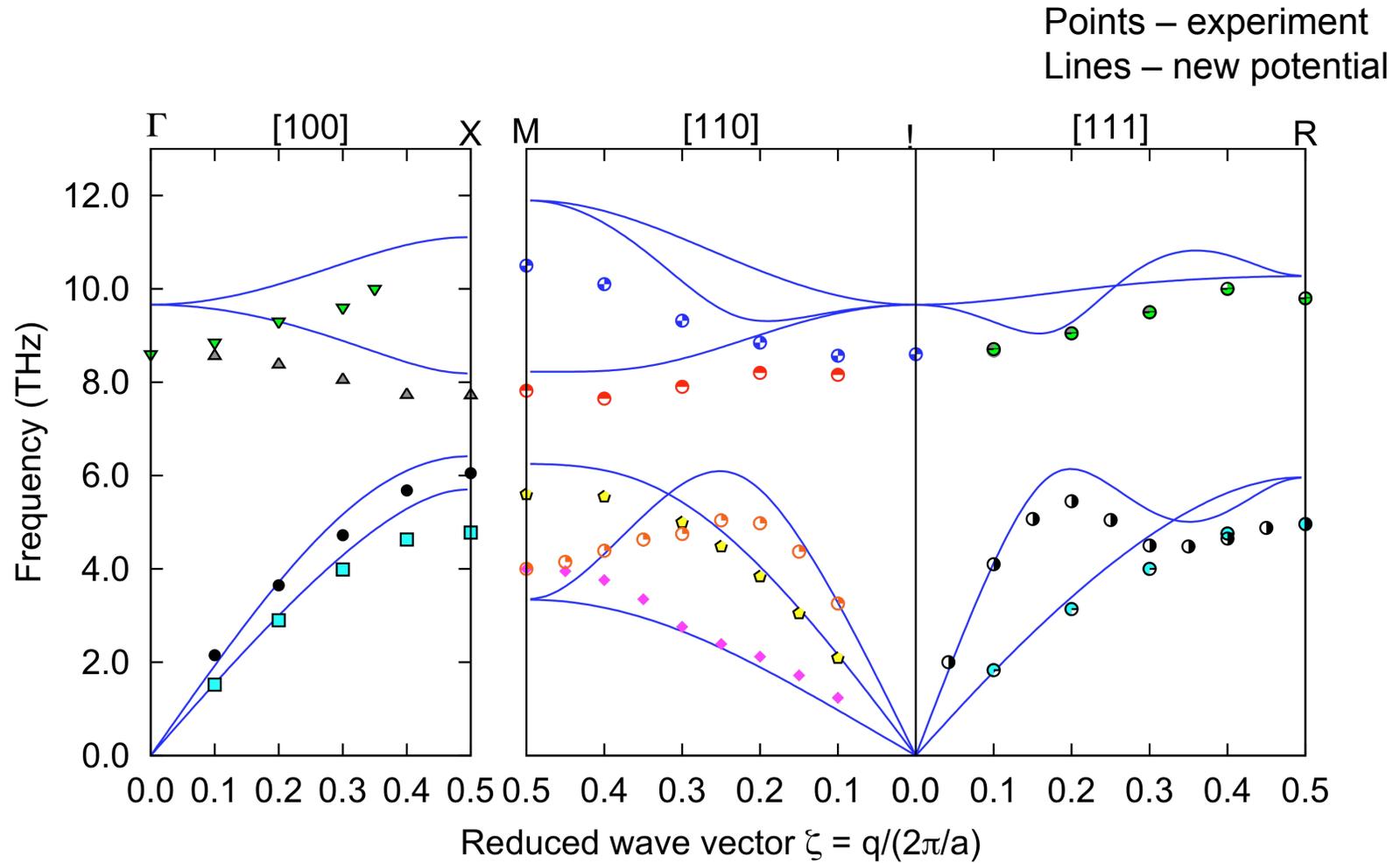


$\langle 111 \rangle \{211\}$ slip

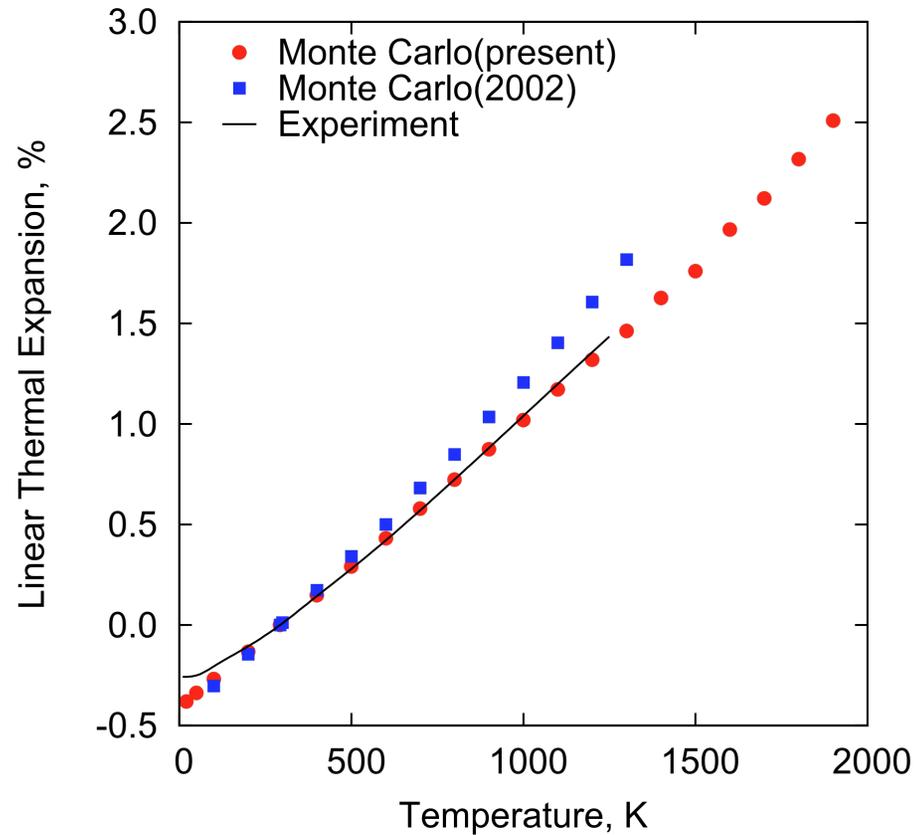


Phonon frequencies in B2-NiAl

Dispersion relations



Thermal expansion of B2-NiAl

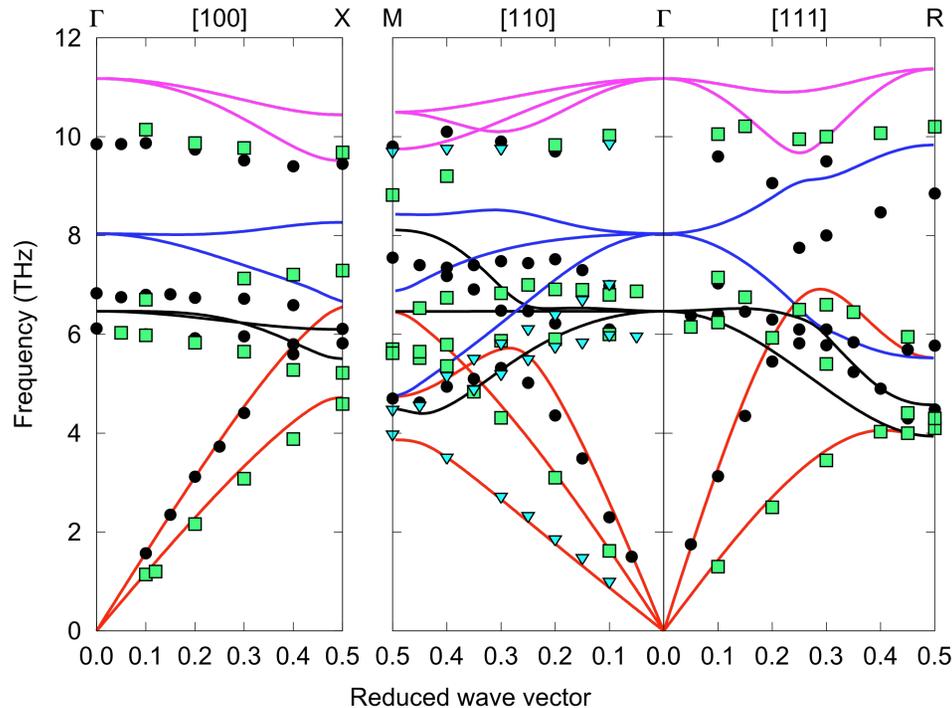


- ◇ Monte-Carlo method
- ◇ Thermal expansion relative to room temperature
- ◇ Significant improvement relative to the “B2-potential” (without fitting)

Properties of Ni₃Al

Lattice properties

	Experiment	EAM (present)	Ni ₃ A- potential
a_0 (Å)	3.57	3.5331	3.571
E_0 (eV)	-4.62	-4.6315	-4.626
c_{11} (GPa)	230	238	236
c_{12} (GPa)	149	166	154
c_{44} (GPa)	132	130	127

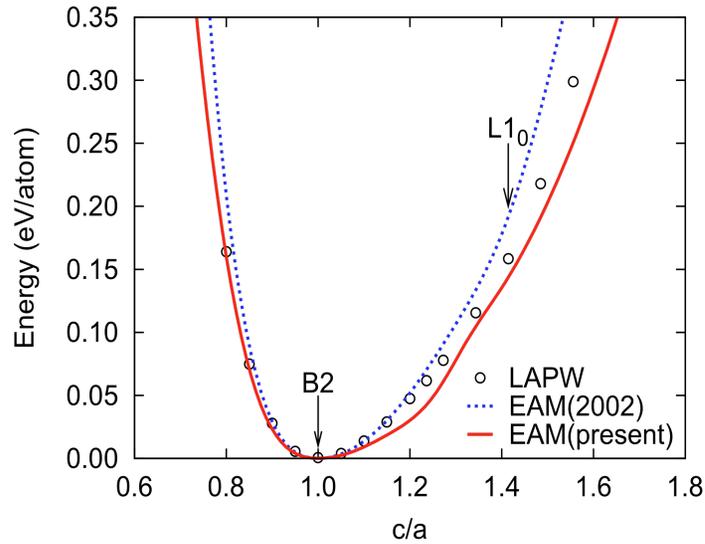


← Phonon frequencies (THz)

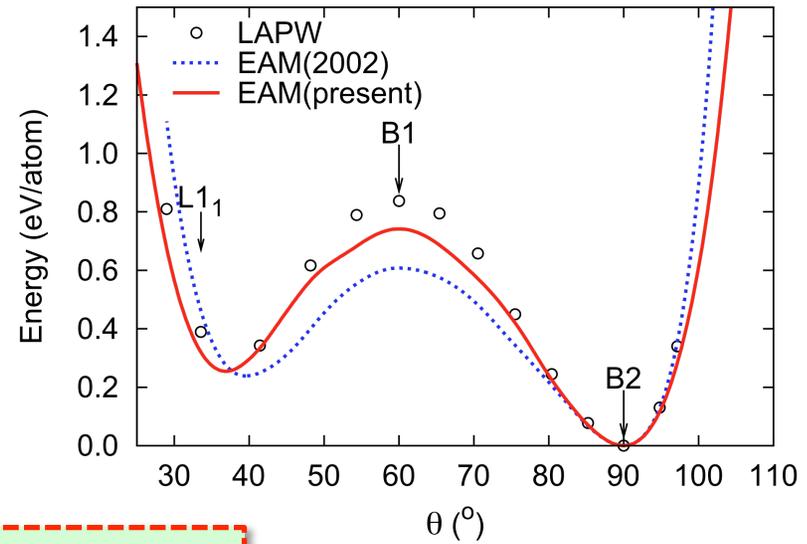
- ◆ Improved phonon frequencies
- ◆ Reasonable elastic constants

Deformation paths between structures

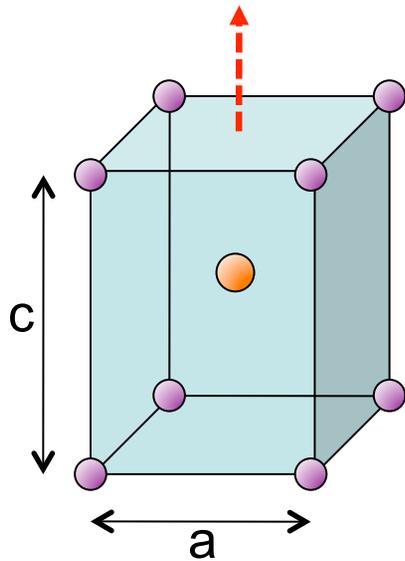
Bain path



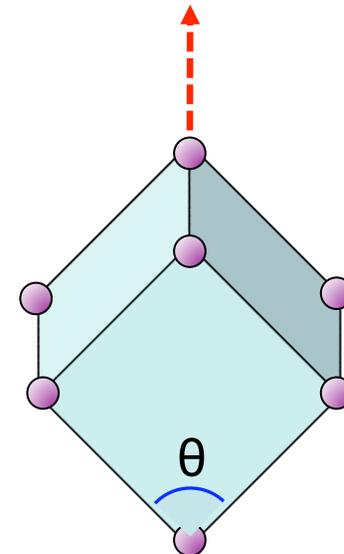
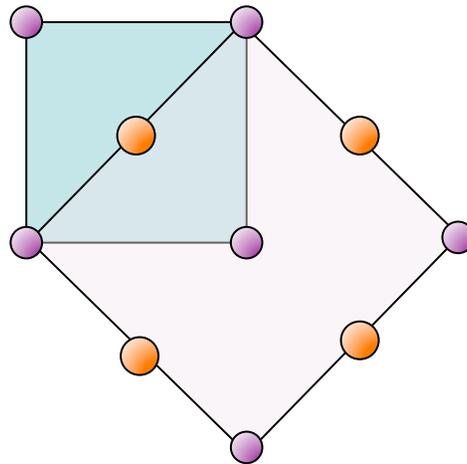
Trigonal path



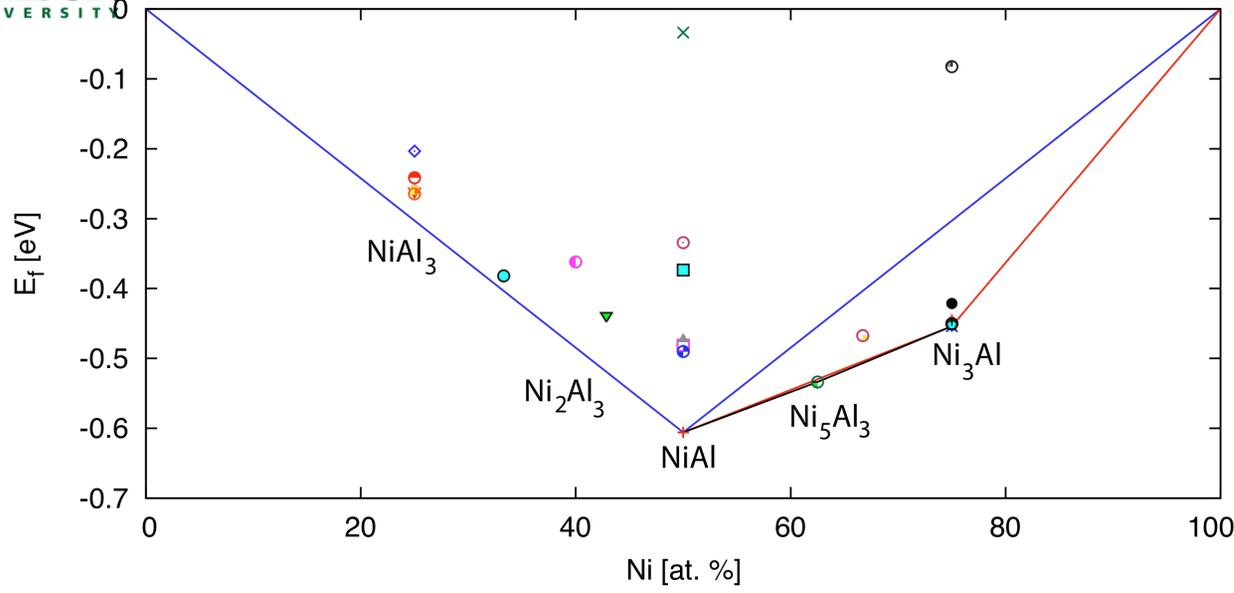
$$V = V_{B2} = \text{const}$$



Top view

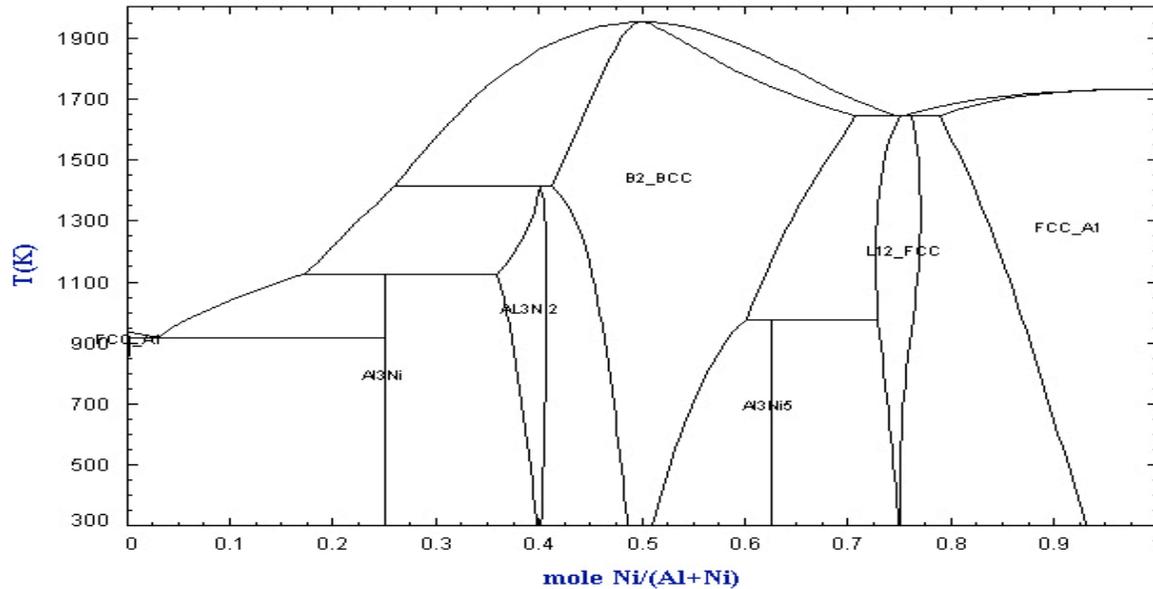


Phase stability in the Ni-Al system



- | | |
|--|--|
| B2:NiAl* + | D0 ₃ :Ni ₃ Al ● |
| B1:NiAl × | D0 ₂ 2:Ni ₃ Al ▲ |
| L1 ₂ :Ni ₃ Al* * | 40:NiAl ▲ |
| L1 ₀ :NiAl □ | L1 ₂ :NiAl ₃ ▼ |
| B32:NiAl ■ | Ga ₄ Ni ₃ :Ni ₃ Al ₄ ▼ |
| L1 ₁ :NiAl ○ | D0 ₃ :NiAl ₃ ◇ |
| D0 ₂₂ :NiAl ₃ ◆ | D0 ₁₁ :NiAl ₃ * ● |
| D0 ₂₃ :Ni ₃ Al ◆ | Ga ₃ Pt ₅ :Ni ₅ Al ₃ * ● |
| D0 ₂₃ :NiAl ₃ ◆ | B20:NiAl ⊕ |
| D0 ₁₉ :Ni ₃ Al ○ | D5 ₁₉ :Ni ₂ Al ₃ * ◆ |
| D0 ₁₉ :NiAl ₃ ○ | C11 _b :NiAl ₂ ● |
| D0 ₁₁ :Ni ₃ Al ○ | C11 _b :Ni ₂ Al ○ |

AI - Ni
Data from BINARY (SGTE) alloy databases



Phase stability is **excellent** on the Ni-rich side but only fair on the Al-rich side

Summary for the Ni-Al potential

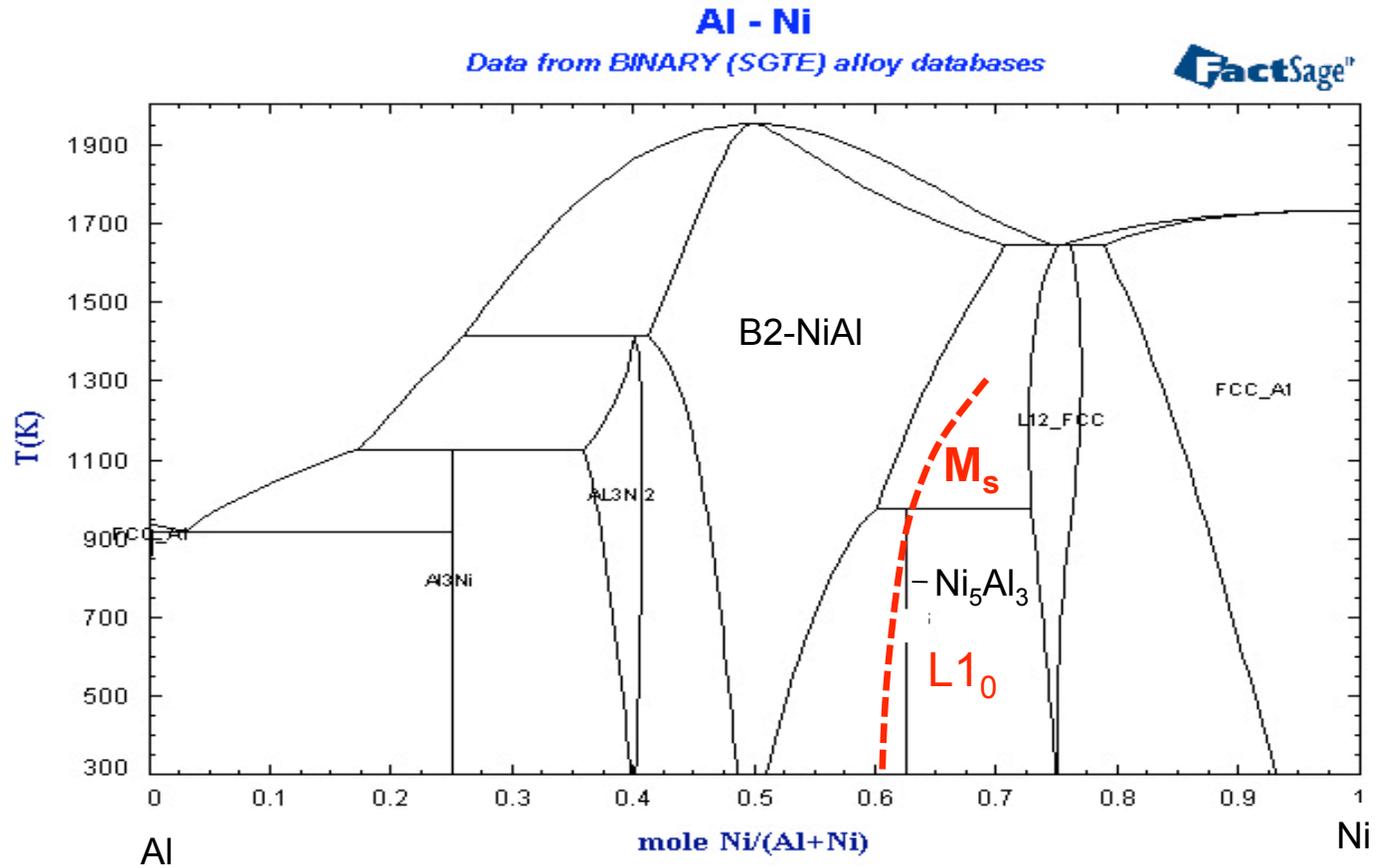
- ⊙ Reproduces many properties of B2-NiAl and L1₂-Ni₃Al in **better** agreement with experimental and *ab initio* data than previous potentials for the Ni-Al system
- ⊙ Demonstrates good “transferability” to various configurations and chemical compositions
- ⊙ Should be suitable for simulations of mechanical properties
- ⊙ The end-members are the “Ni-04” and “Al-99” potentials

Investigation of the martensitic transformation in Ni-Al shape-memory alloys

NiAl shape memory alloys: background

- **Shape memory effect** in Ni-rich $\text{Ni}_x\text{Al}_{1-x}$ alloys ($x = 0.60-0.64$) was discovered in the early 1970s.
- The shape memory effect is explained by a **martensitic phase transformation** $\text{B2} \rightarrow \text{L1}_0$. The transformation does not require any diffusion and occurs at low temperatures.
- The martensitic structure usually contains multiple twins and stacking faults. The stacking faults can form long-period ordered structures such as 7M.
- The transformation is accompanied by a significant hysteresis.
- The martensite-start (M_s) and austenite-finish (A_f) temperatures, as well as the martensite structure depend sensitively on the chemical composition, cooling/heating rate, the microstructure (grain boundaries, dislocations, etc.) and other factors.
- Annealed martensite may contain ordered precipitates of Ni_5Al_3 and/or Ni_3Al .
- Martensitic transformation at the crack tip in B2-NiAl was found experimentally and by simulations.

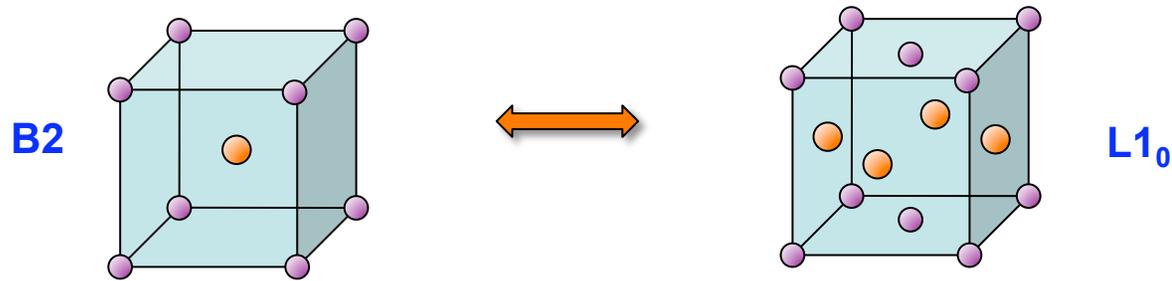
Where is it on the phase diagram?



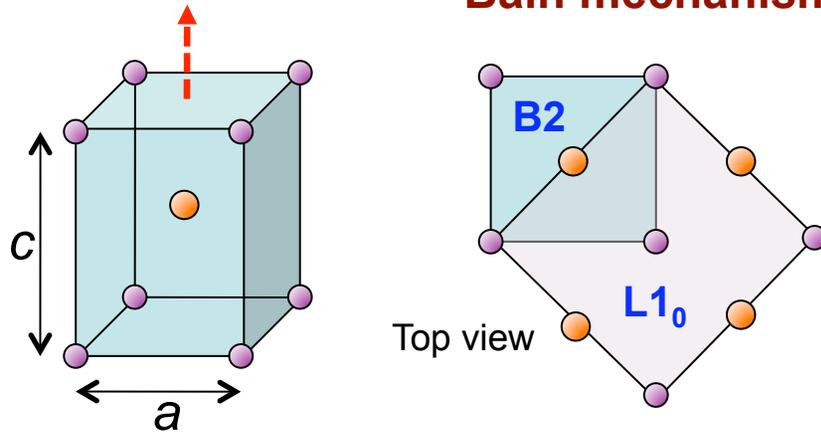
Atomistic simulations of the NiAl martensite: Status of the field

- Clapp and co-workers (1990s) were the first to study this transformation, focusing on the effect of grain boundaries, surfaces and other defects. Used the Voter-Chen Ni-Al potential (1987), which unfortunately incorrectly predicts $L1_0$ (not B2) to be the ground state for the 50:50 composition.
- Lazarev et al. (2004, 2005) studied the transformation using the potential of Farkas et al. (1995) who refitted the Voter-Chen potential to give the correct ground state. Examined the effects of composition, stresses and defects.
- Guo et al. (2007) simulated crack growth in B2-NiAl and found the martensitic transformation at the crack tip. Used the Farkas potential.
- Many authors (e.g. Ackland, Elliott, Van der Ven) published excellent studies of martensitic transformations in other systems.

Crystallography of the B2-L1₀ transformation



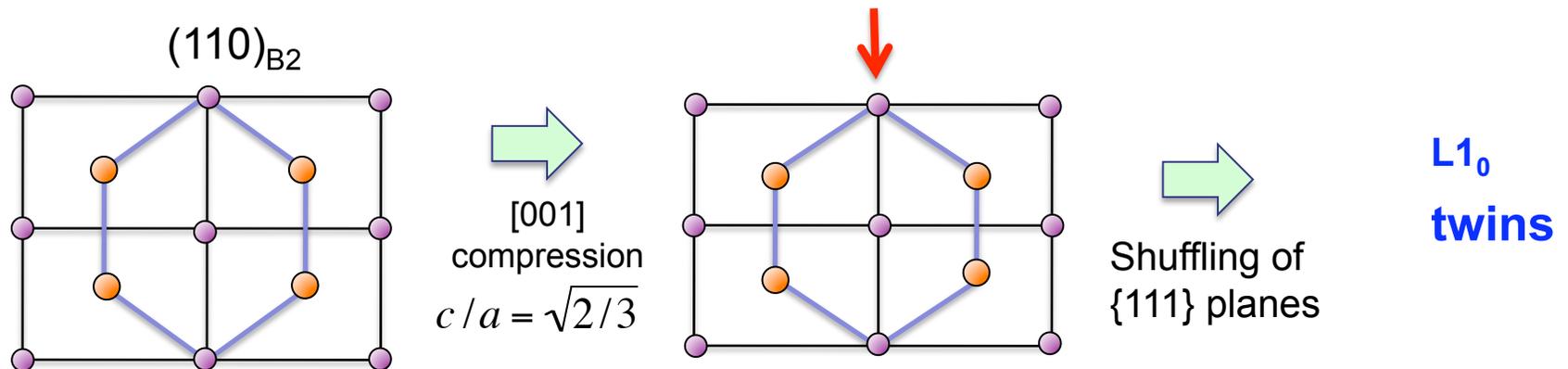
Bain mechanism:



B2: $c/a = 1$ L1₀: $1 < c/a < \sqrt{2}$



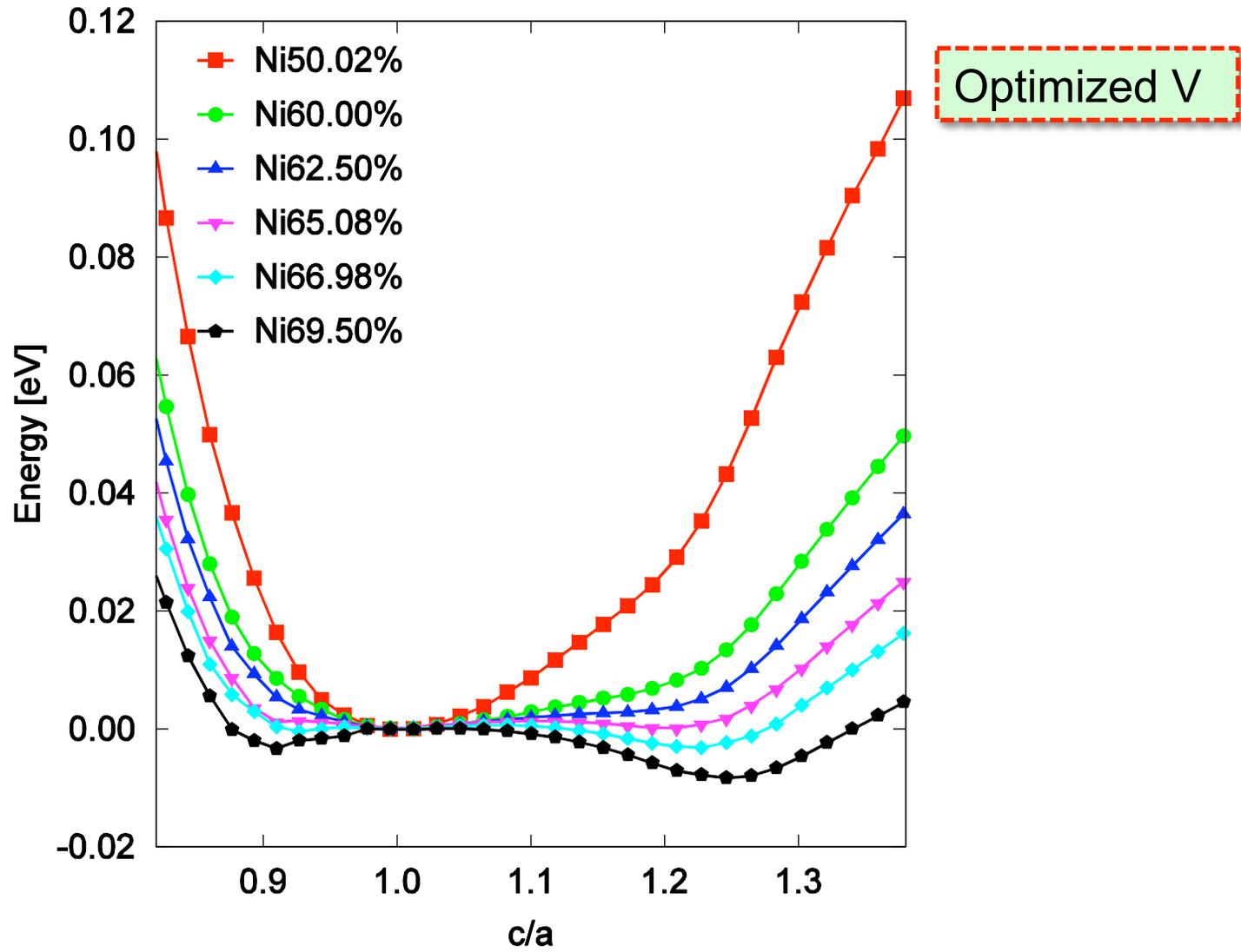
Shuffling mechanism:



Methodology of simulations

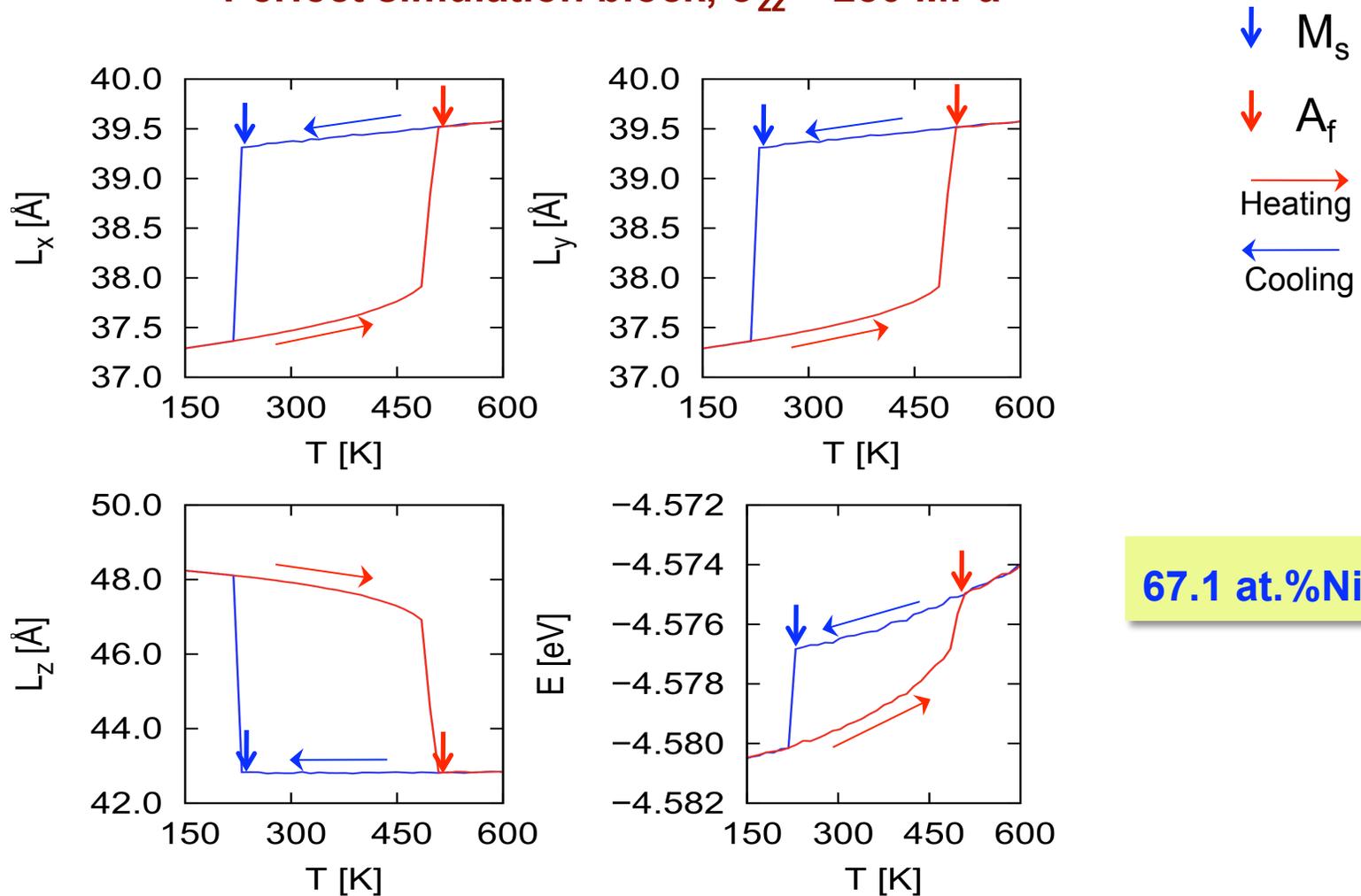
- The new Ni-Al potential.
- Rectangular simulation block with fully periodic boundary conditions. Initial structure B2. Orientations of the axes: [-110], [110], [001].
- Grand-canonical Monte Carlo (NPT) simulations at $T = 1200$ K with chemical potentials adjusted to give desired Ni-rich chemical compositions.
- Switch to MD simulations in the NPT ensemble at the same temperature and fixed values of the stresses σ_{xx} , σ_{yy} and σ_{zz} .
- Decrease temperature down to 0 K and monitor the block dimensions and energy. Observe the martensitic transformation.
- Increase temperature up to 1200 K and observe the austenitic transformation
- Cooling/heating rate 10^{11} K/s affects the M_s and A_f temperatures.
- Repeat at different tensile/compressive stresses σ_{zz} (with $\sigma_{xx} = \sigma_{yy} = 0$) to study the stress effect on the transformations.
- Repeat in the presence of a (110) APB, open surface, dislocations – to model microstructure effects

B2-L1₀ transformation path at T = 0 K



Demonstration of the shape memory effect

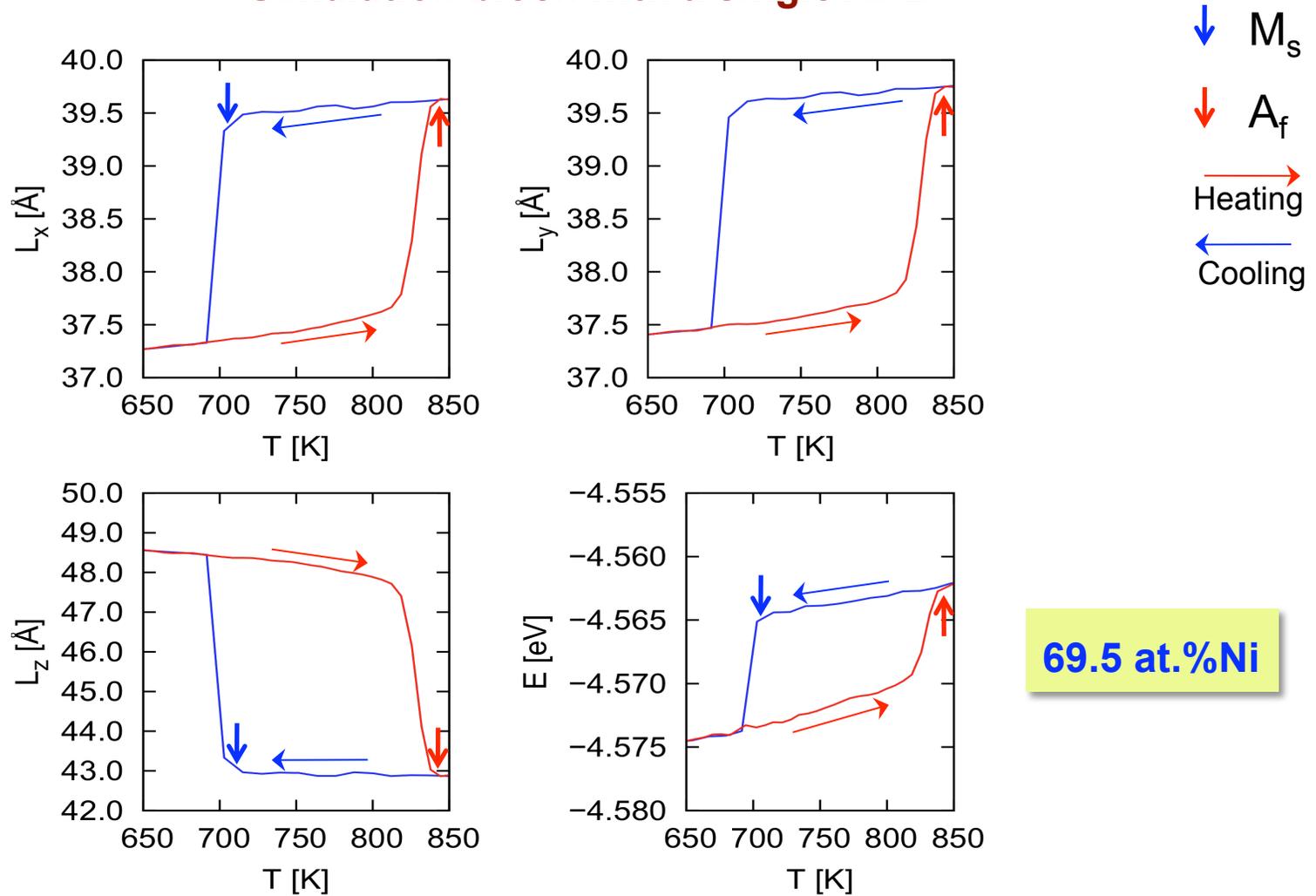
Perfect simulation block, $\sigma_{zz} = 280$ MPa



\rightarrow Complete reversibility of the crystal structure and shape!

Demonstration of the shape memory effect

Simulation block with a single APB

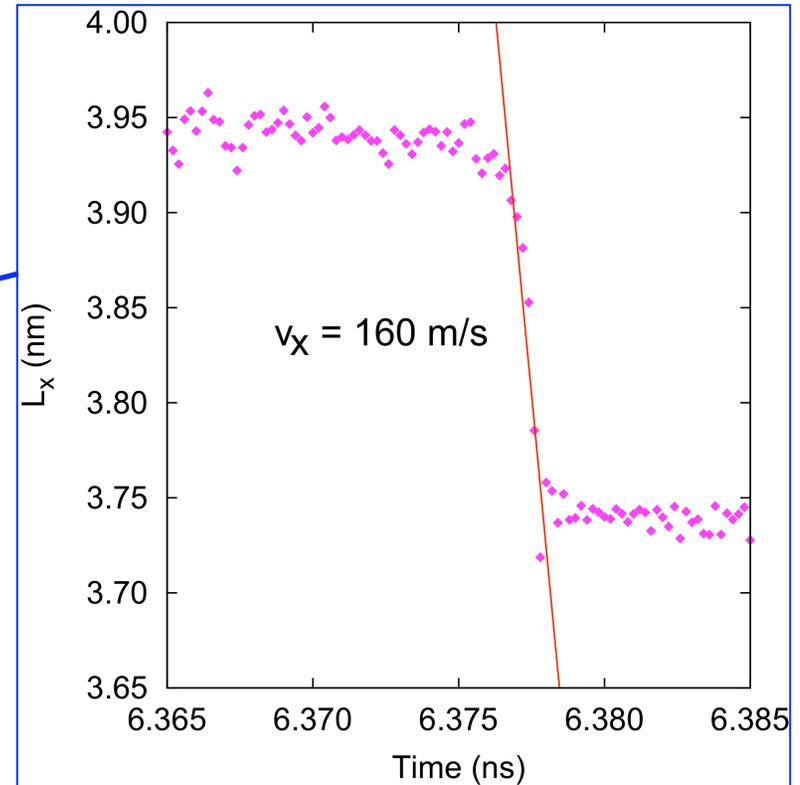
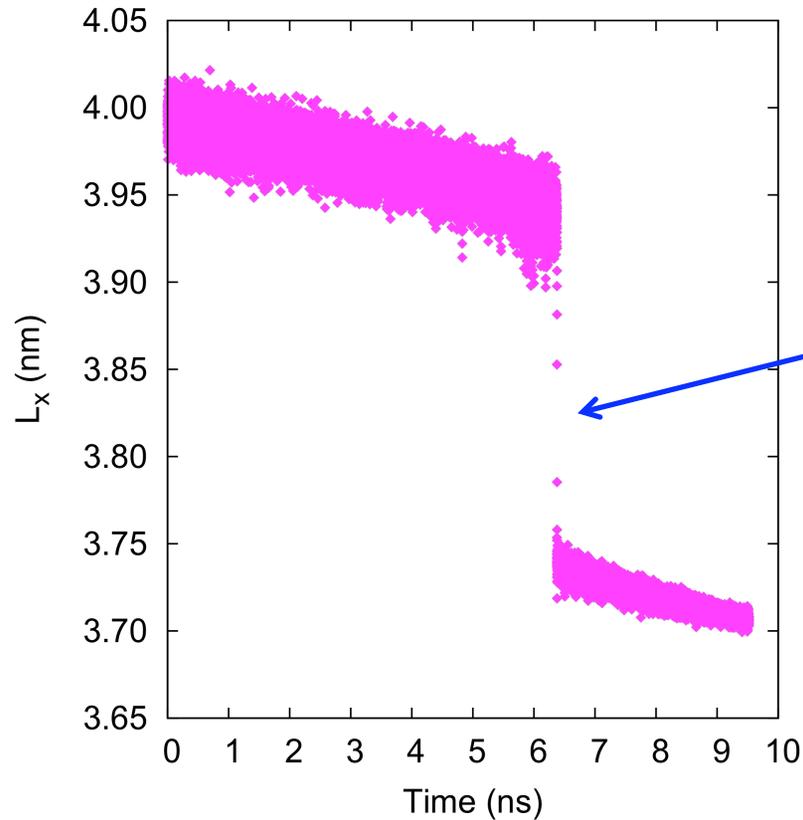


\rightarrow Complete reversibility of the crystal structure and shape!

How fast does this happen?

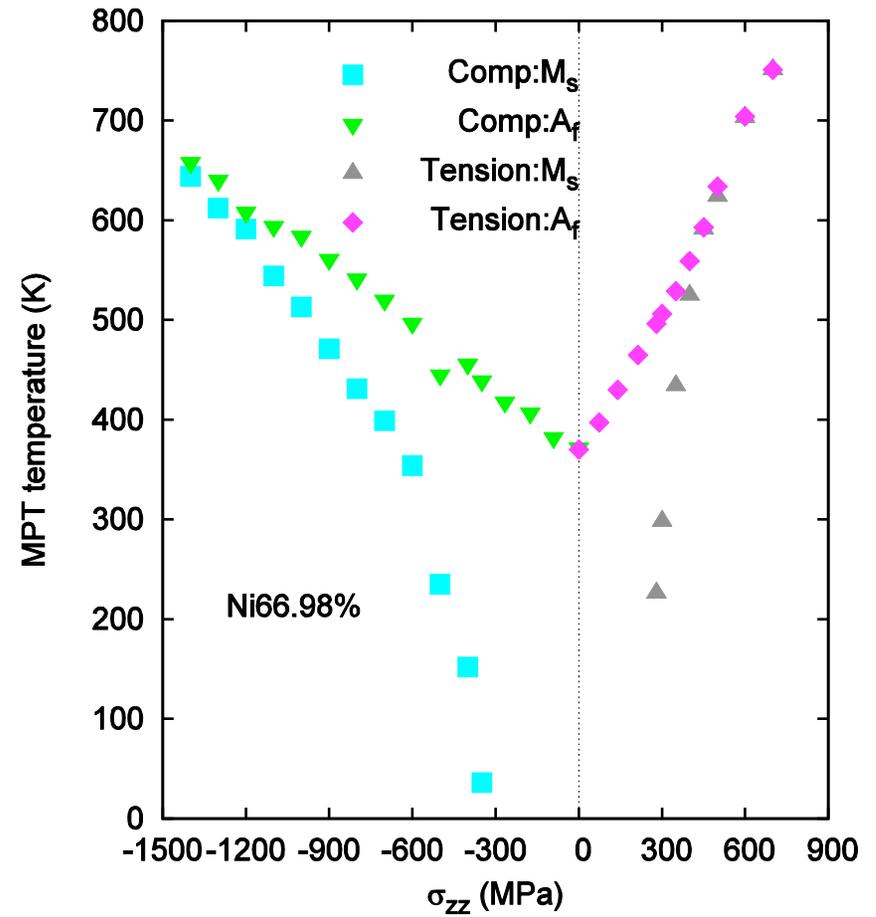
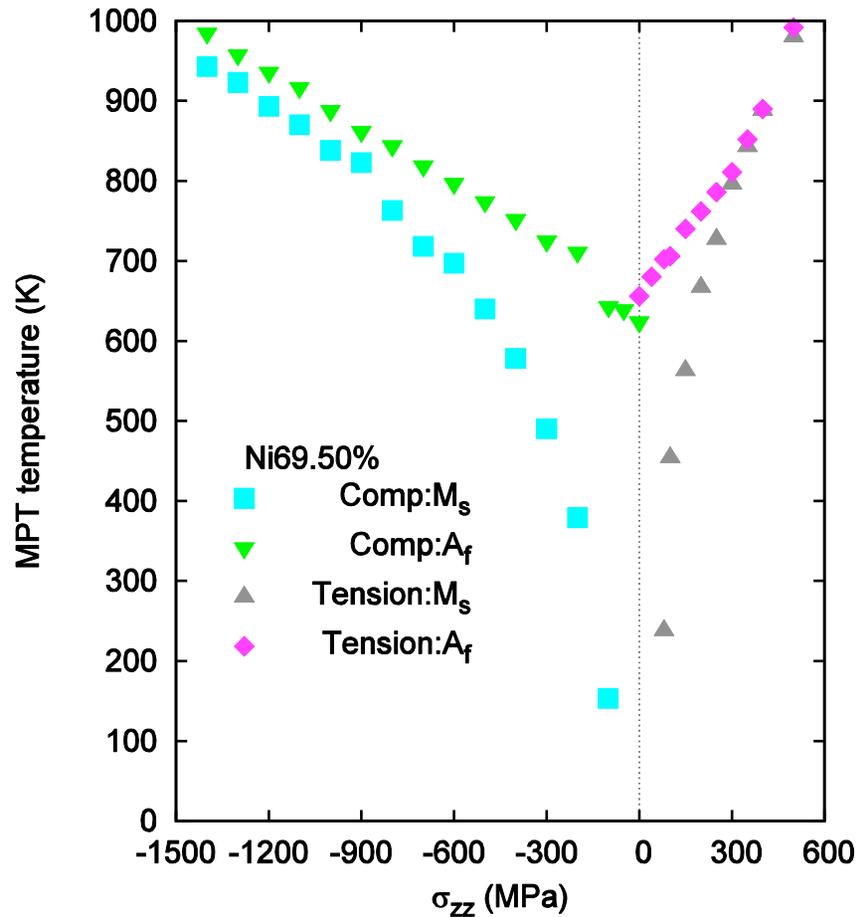
69.5 at.%Ni

$\sigma_{zz} = 280$ MPa

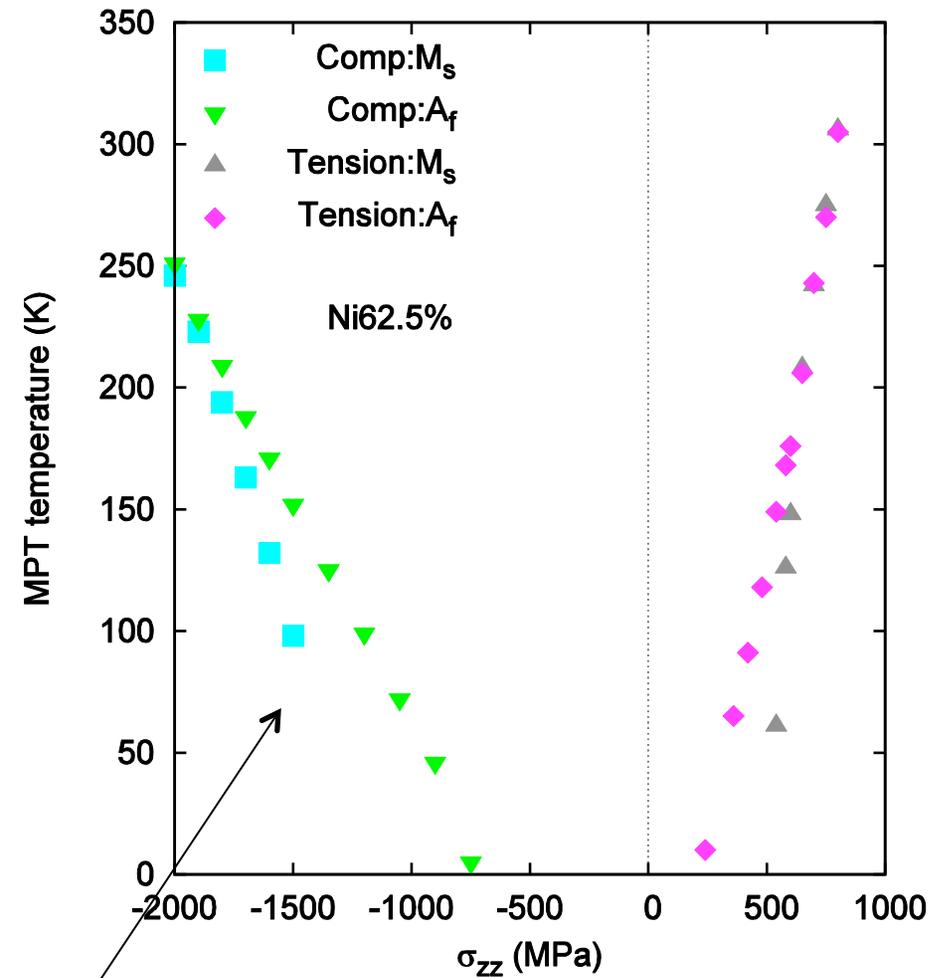
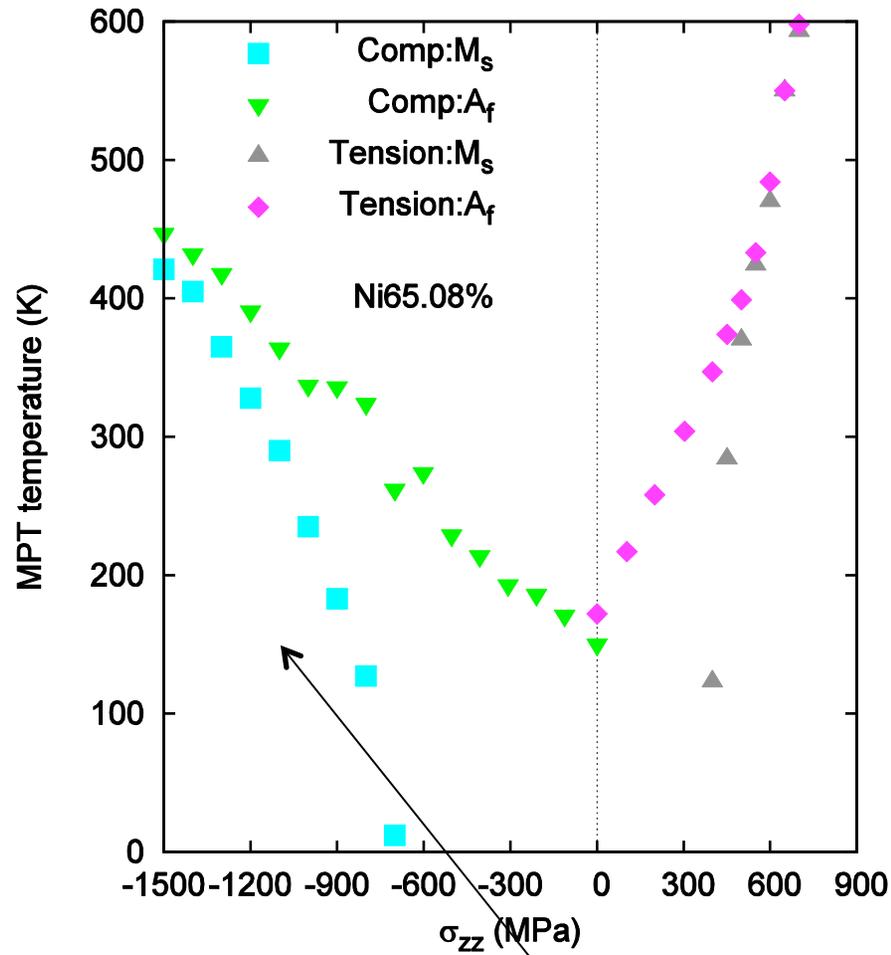


Typical speeds at M_s are 100-300 m/s

Effect of stress on the transformation



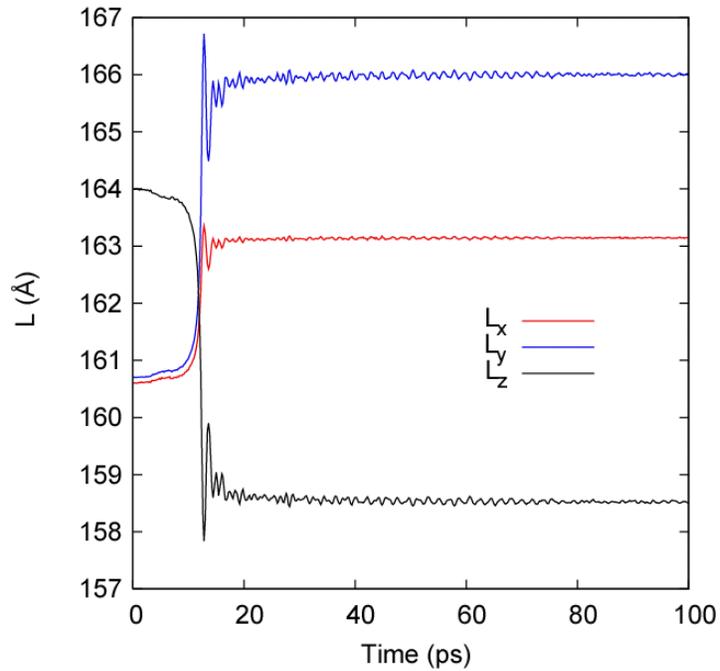
Effect of stress on the transformation



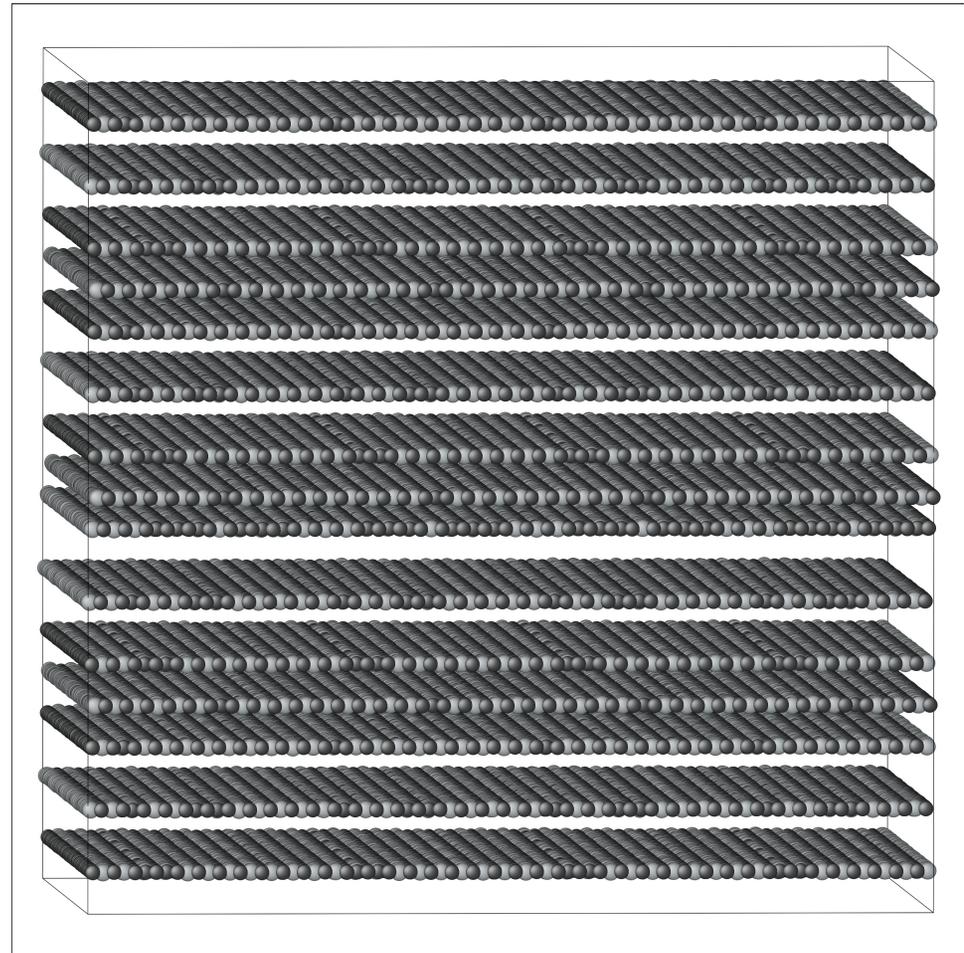
Twinned martensite

Twinned martensite formation

Isothermal annealing at 94 K, compression 800 MPa

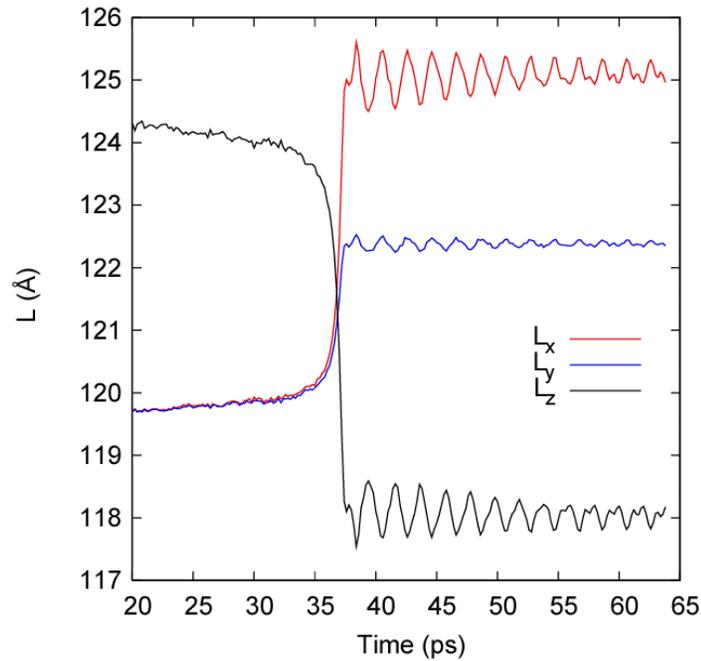


N=384,000 atoms
Composition: 65.08%Ni

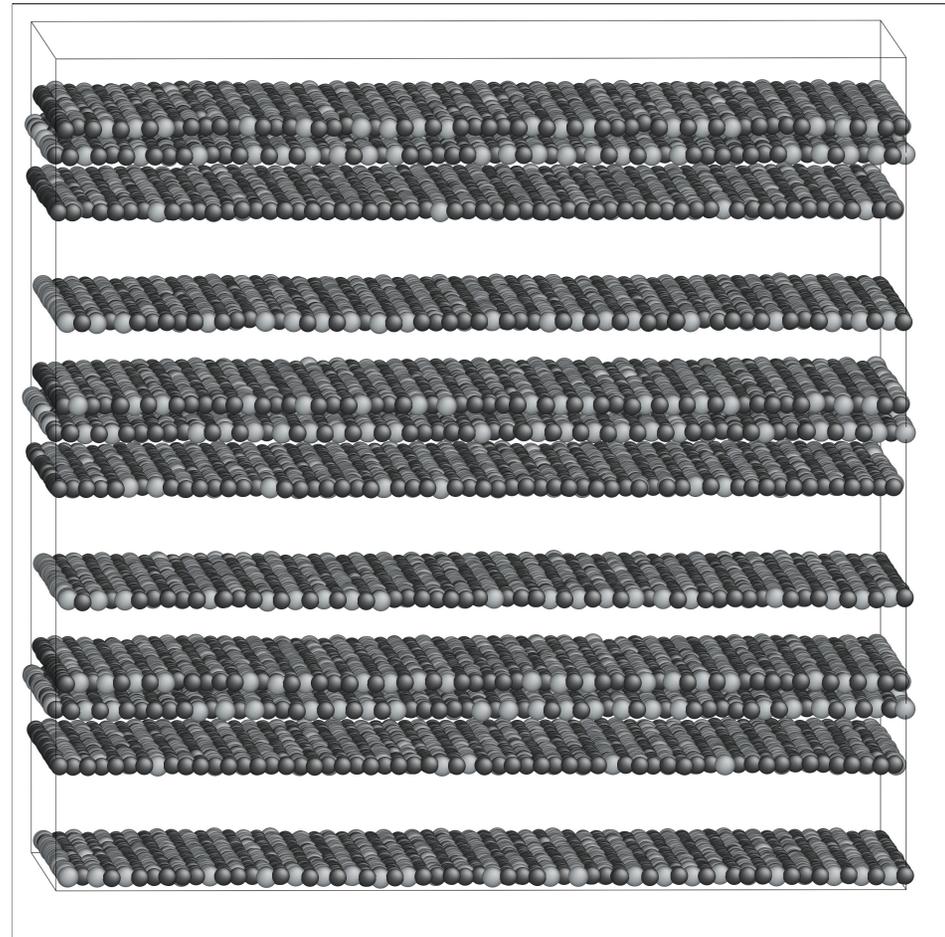


Twinned martensite formation

Isothermal annealing at 310 K, compression 200 MPa



N=162,000 atoms
Composition: 69.50%Ni



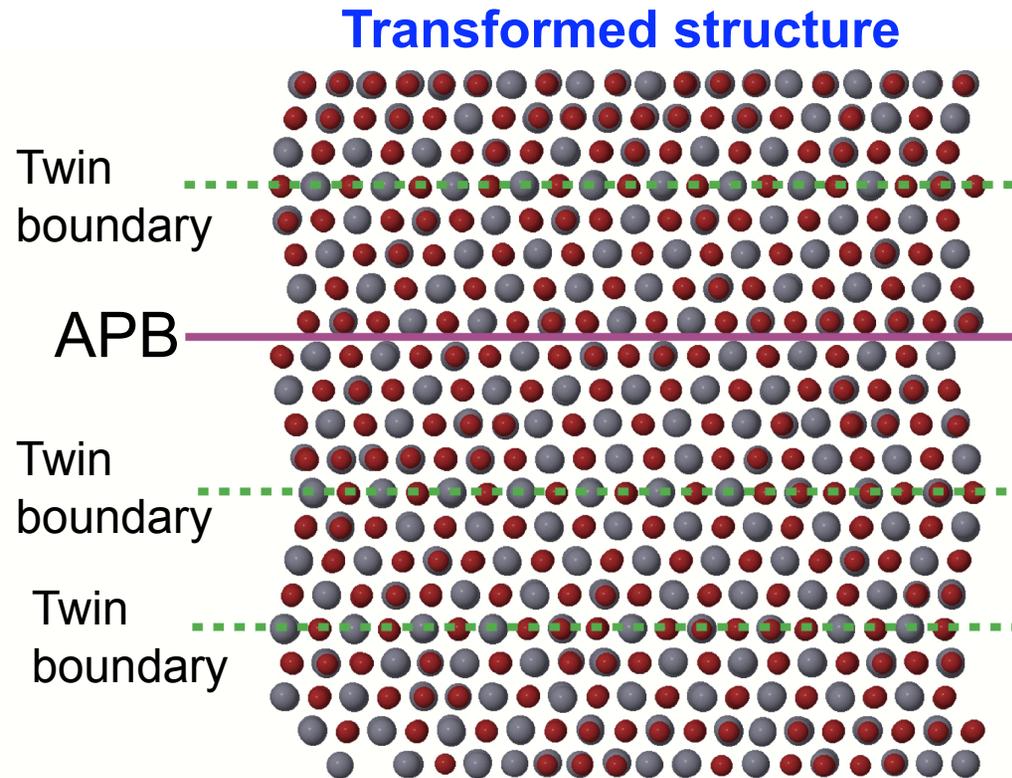
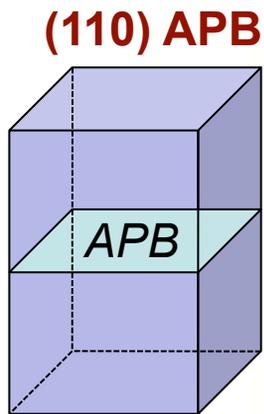
Effect of defects on the transformation

69.5at.%Ni

(110) APB: $A_f = 827 \text{ K}$; $M_s = 700 \text{ K}$
 Perfect lattice: $A_f = 652 \text{ K}$; $M_s = ?$

67.0at.%Ni

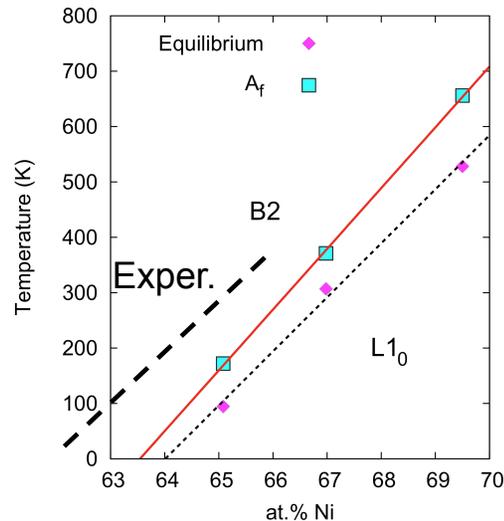
(110) APB: $A_f = 467 \text{ K}$; $M_s = 204 \text{ K}$
 Perfect lattice: $A_f = 372 \text{ K}$; $M_s = ?$



Jmol

The APB increases M_s and A_f and induces twinning of the martensite

Summary for the martensitic transformation



- The transformation is fully reversible both in the perfect lattice and in the presence of defects.
 - The transformation is strongly controlled by the nucleation process. The martensite/austenite growth is very fast.
 - The transformation temperature depends on the cooling/heating rate. Reducing the cooling rate increases M_s . At the extremely high cooling rates implemented in our simulations, homogeneous nucleation at zero pressure could not be observed.
-
- Tensile and compressive stresses along [001] increase the transformation temperatures (M_s and A_f) and reduce the hysteresis.
 - Lattice defects assist the martensite nucleation and increase M_s . But they can also lead to twinned martensite with relatively high A_f .
 - The potential shifts the transformation line to higher Ni concentrations in comparison with experiment. However, experimental samples contain internal stresses and Ni segregation at defects.